NSN 5962-01-317-4147

Memory Microcircuit - Page 1 of 1

Fiig: A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-317-4147 **Body Length:** 0.925 inches **Body Width:** 0.302 inches **Body Height:** 0.175 inches **Maximum Power Dissipation Rating:** 409.6 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli